



SPECIFICATION

• Supplier : Samsung electro-mechanics • Samsung P/N : CL21A105KPFNNNG

• Product : Multi-layer Ceramic Capacitor • Description : CAP, 1 µF, 10V, ±10%, X5R, 0805

A. Samsung Part Number

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1	Series	Samsung Multi-layer Ceramic Capacitor							
2	Size	0805 (inch co	ode) L	.: 2.0	± 0.1	mm	W:	1.25 ± 0.1	mm
3	Dielectric	X5R		8	Inner e	electrode		Ni	
4	Capacitance	1 μF			Termin	nation		Cu	
(5)	Capacitance	±10 %			Plating	J	;	Sn 100%	(Pb Free)
	tolerance			9	Produc	ct		Normal	
6	Rated Voltage	10 V		10	Specia	ıl		Reserved for	future use
7	Thickness	1.25 ± 0.1	mm	11	Packag	ging		Embossed T	ype,7 "reel(3,000ea)

B. Samsung Reliablility Test and Judgement condition

	Performance	Test condition					
Capacitance	Within specified tolerance	1kltz±10% 1.0±0.2Vrms					
Tan δ (DF)	0.05 max.						
Insulation	More than 100Mohm⋅ <i>μ</i> F	Rated Voltage 60~120 sec.					
Resistance							
Appearance	No abnormal exterior appearance	Visual inspection					
Withstanding	No dielectric breakdown or	250% of the rated voltage					
Voltage	mechanical breakdown						
Temperature	X5R						
Characteristics	(From -55℃ to 85℃, Capacitance change should be within ±15%)						
Adhesive Strength	No peeling shall be occur on the	500g·F, for 10±1 sec.					
of Termination	terminal electrode						
Bending Strength	Capacitance change : within ±12.5%	Bending to the limit (1mm)					
		with 1.0mm/sec.					
Solderability	More than 75% of terminal surface	SnAg3.0Cu0.5 solder					
	is to be soldered newly	245±5°C, 3±0.3sec.					
		(preheating : 80~120℃ for 10~30sec.)					
Resistance to	Capacitance change : within ±7.5%	Solder pot : 270±5 ℃, 10±1sec.					
Soldering heat	Tan δ, IR : initial spec.						

	Performance	Test condition				
Vibration Test	Capacitance change : within ±5%	Amplitude : 1.5mm				
	Tan δ, IR : initial spec.	From 10Hz to 55Hz (return : 1min.)				
		2hours × 3 direction (x, y, z)				
Moisture	Capacitance change: within ±12.5%	With rated voltage				
Resistance	Tan δ : 0.075 max	40±2℃, 90~95%RH, 500 +12/-0 hours				
	IR : More than 25№ μF					
High Temperature	Capacitance change : within ±12.5%	With 200% of the rated voltage				
Resistance	Tan δ : 0.075 max	Max. operating temperature				
	IR : More than 50ΜΩ·μF					
		1000+48/-0 hours				
Temperature	Capacitance change : within ±7.5%	1 cycle condition				
Cycling	Tan δ, IR : initial spec.	Min. operating temperature → 25 °C				
		$ ightarrow$ Max. operating temperature $ ightarrow$ 25 $^{\circ}\mathrm{C}$				
		5 cycles test				

C. Recommended Soldering method :

Reflow (Reflow Peak Temperature : 260+0/-5 $^{\circ}$ C, 10sec. Max)

^{*} For the more detail Specification, Please refer to the Samsung MLCC catalogue.